NSN 5961-01-115-6663

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Inclosure Material:

Metal

Overall Length:

0.260 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.370 inches

End Application:

4920-01-046-1613

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-5

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 breakdown voltage, collector-to-base, emitter open and 4.0 breakdown voltage, collector-to-emitter, base open and 200.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

1.00 amperes source cutoff current and 500.00 milliamperes source cutoff current

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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